



SN74LVC1GX04

SCES581D-JULY 2004-REVISED OCTOBER 2015

SN74LVC1GX04 Crystal Oscillator Driver

Technical

Documents

Sample &

Buv

1 Features

- Available in Texas Instruments NanoStar[™] and NanoFree[™] Packages
- Supports 5-V V_{CC} Operation
- Inputs Accept Voltages to 5.5 V
- One Unbuffered Inverter (SN74LVC1GU04) and One Buffered Inverter (SN74LVC1G04)
- Suitable for Commonly Used Clock Frequencies:
 - 15 kHz, 3.58 MHz, 4.43 MHz, 13 MHz, 25 MHz, 26 MHz, 27 MHz, 28 MHz
- Maximum t_{pd} of 2.4 ns at 3.3 V
- Low Power Consumption, 10-µA Maximum I_{CC}
- ±24-mA Output Drive at 3.3 V
- Ioff Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human Body Model (A114-A)
 - 1000-V Charged-Device Model (C101)

2 Applications

- Crystal Oscillators
- Clock Generation

3 Description

Tools &

Software

The SN74LVC1GX04 device is designed for 1.65-V to 5.5-V V_{CC} operation. This device incorporates the SN74LVC1GU04 (inverter with unbuffered output) and the SN74LVC1G04 (inverter) functions into a single device. The LVC1GX04 is optimized for use in crystal oscillator applications.

Support &

Community

20

X1 and X2 can be connected to a crystal or resonator in oscillator applications. The device provides an additional buffered inverter (Y) for signal conditioning (see Figure 5). The additional buffered inverter improves the signal quality of the crystal oscillator output by making it rail to rail.

NanoStar and NanoFree package technology is a major breakthrough in IC packaging concepts, using the die as the package.

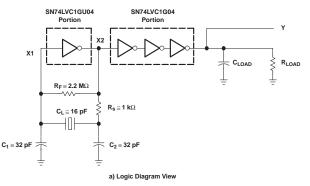
This device is fully specified for partial-power-down applications using I_{off} (Y output only). The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

Device Information⁽¹⁾

| PART NUMBER | PACKAGE | BODY SIZE (NOM) |
|---------------------|------------|-------------------|
| SN74LVC1GX04DB V | SOT-23 (6) | 2.90 mm × 1.60 mm |
| SN74LVC1GX04DC K | SC70 (6) | 2.00 mm × 1.25 mm |
| SN74LVC1GX04DR L | SOT (6) | 1.60 mm × 1.20 mm |

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Functional Block Diagram



SN74LVC1GX04 includes both dotted portions



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4 Revision History

Changes from Revision C (December 2013) to Revision D

Added Pin Configuration and Functions section, ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device

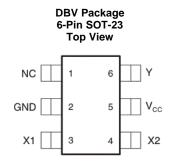
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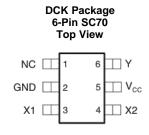
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5 Pin Configuration and Functions





| DRL Package 6-Pin SOT Top View | | | | | | | | |
|--------------------------------------|---|---|-------------------|--|--|--|--|--|
| NC 🗆 | 1 | 6 | ΡY | | | | | |
| GND 🗆 | 2 | 5 | □ V _{cc} | | | | | |
| X1 🗆 | 3 | 4 | □ X2 | | | | | |

See mechanical drawings for dimensions.

NC - No internal connection.

Pin Functions

| PIN | | 1/0 | DESCRIPTION | | |
|------|-----|-----|----------------------------|--|--|
| NAME | NO. | I/O | DESCRIPTION | | |
| GND | 2 | _ | Ground | | |
| NC | 1 | - | No internal connection | | |
| VCC | 5 | - | Supply power | | |
| X1 | 3 | I | Amplifier input | | |
| X2 | 4 | 0 | Amplifier output | | |
| Y | 6 | 0 | Main output to other logic | | |

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

| | | | MIN | MAX | UNIT |
|------------------|---|--------------------------------|------|-----------------------|------|
| V _{CC} | Supply voltage | | -0.5 | 6.5 | V |
| VI | Input voltage ⁽²⁾ | | -0.5 | 6.5 | V |
| Vo | Voltage applied to Y output in the high-impedance or | power-off state ⁽²⁾ | -0.5 | 6.5 | V |
| Vo | Voltage applied to any output in the high or low state ^{(2) (3)} | | -0.5 | V _{CC} + 0.5 | V |
| I _{IK} | Input clamp current | V ₁ < 0 | | -50 | mA |
| I _{OK} | Output clamp current | V _O < 0 | | -50 | mA |
| lo | Continuous output current | | | ±50 | mA |
| | Continuous current through V _{CC} or GND | | | ±100 | mA |
| TJ | Junction temperature | | | 150 | °C |
| T _{stg} | Storage temperature | | -65 | 150 | °C |

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The value of V_{CC} is provided in the recommended operating conditions table.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|--------------------|--|---|-------|------|
| V | Electrostatic | Human body model (HBM), per AEC Q100-002 ⁽¹⁾ | ±2000 | |
| V _(ESD) | discharge Charged-device model (CDM), per AEC Q100-011 | Charged-device model (CDM), per AEC Q100-011 | ±1000 | v |

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions⁽¹⁾

| | | | MIN | MAX | UNIT |
|-----------------|---------------------------|--|------------------------|----------------------|------|
| | | Operating | 1.65 | 5.5 | |
| V_{CC} | Supply voltage | Data retention only | 1.5 | | V |
| | | Crystal oscillator use | 2 | | |
| VIH | High-level input voltage | V _{CC} = 1.65 V to 5.5 V | 0.75 × V _{CC} | | V |
| VIL | Low-level input voltage | V _{CC} = 1.65 V to 5.5 V | | $0.25 \times V_{CC}$ | V |
| VI | Input voltage | | 0 | 5.5 | V |
| | Outrout welte an | X2, Y | 0 | V _{CC} | V |
| Vo | Output voltage | Y output only, Power-down mode, $V_{CC} = 0 V$ | 0 | 5.5 | v |
| | | V _{CC} = 1.65 V | | -4 | |
| | | V _{CC} = 2.3 V | | -8 | |
| I _{OH} | High-level output current | ligh-level output current $V_{CC} = 3 V$ | | -16 | mA |
| | | | | -24 | |
| | | $V_{CC} = 4.5 V$ | | -32 | |
| | | V _{CC} = 1.65 V | | 4 | |
| | | V _{CC} = 2.3 V | 8 | | |
| I _{OL} | Low-level output current | <u> </u> | | 16 | mA |
| | | $V_{CC} = 3 V$ | | 24 | |
| 1 | | V _{CC} = 4.5 V | | 32 | |

 All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, SCBA004.



Recommended Operating Conditions⁽¹⁾ (continued)

| | | | MIN | MAX | UNIT |
|----------------|--|--|-----|-----|------|
| | V_{CC} = 1.8 V ± 0.15 V, 2.5 V ± 0.2 V | | 20 | | |
| Δt/Δv | $\Delta t/\Delta v$ Input transition rise or fall rate | $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | | 10 | ns/V |
| | | $V_{CC} = 5 V \pm 0.5 V$ | | 10 | |
| T _A | Operating free-air temperature | | -40 | 125 | °C |

6.4 Thermal Information

| | | SN74LVC1GX04 | | | |
|-----------------|--|--------------|------------|-----------|------|
| | THERMAL METRIC ⁽¹⁾ | DBV (SOT-23) | DCK (SC70) | DRL (SOT) | UNIT |
| | | 6 PINS | 6 PINS | 6 PINS | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 165 | 259 | 142 | °C/W |

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

| PARA | METER | | TEST CONDITIONS | i | V _{cc} | MIN | TYP ⁽¹⁾ | MAX | UNIT |
|------------------|--------------------------|---|---------------------------------|---|-----------------|-----------------------|--------------------|------|------|
| V _{он} | | I _{OH} = −100 μA | | | 1.65 V to 5.5 V | V _{CC} - 0.1 | | | |
| | | $I_{OH} = -4 \text{ mA}$ | | | 1.65 V | 1.2 | | | |
| | $I_{OH} = -8 \text{ mA}$ | V ₁ = 5.5 V or GND | T _A = -40°C to 125°C | 2.3 V | 1.9 | | | V | |
| | | I _{OH} = -16 mA | v ₁ = 5.5 v or GND | $T_A = -40 \text{ C to } 125 \text{ C}$ | 3 V | 2.4 | | | v |
| | | $I_{OH} = -24 \text{ mA}$ | | | 3 V | 2.3 | | | |
| | | $I_{OH} = -32 \text{ mA}$ | | | 4.5 V | 3.8 | | | |
| | I _{OL} = 100 μA | | | 1.65 V to 5.5 V | | | 0.1 | | |
| | | $I_{OL} = 4 \text{ mA}$ | V ₁ = 5.5 V or GND | $T_A = -40^{\circ}C$ to $125^{\circ}C$ | 1.65 V | | | 0.45 | |
| | | I _{OL} = 8 mA | | | 2.3 V | | | 0.3 | |
| V | | I _{OL} = 16 mA | | $T_A = -40^{\circ}C$ to $125^{\circ}C$ | 3 V | | | 0.4 | V |
| V _{OL} | | 1 04 mA | | $T_A = -40^{\circ}C$ to $85^{\circ}C$ | - 3 V | | | 0.55 | v |
| | | $I_{OL} = 24 \text{ mA}$ | | $T_A = -40^{\circ}C$ to $125^{\circ}C$ | 3 V | | | 0.63 | |
| | | 1 30 m A | | $T_A = -40^{\circ}C$ to $85^{\circ}C$ | - 4.5 V | | | 0.55 | |
| | | I _{OL} = 32 mA | | $T_A = -40^{\circ}C$ to $125^{\circ}C$ | 4.5 V | | | 0.7 | |
| I _I | X1 | $V_1 = 5.5 \text{ V or GND}$ | $T_{A} = -40^{\circ}C$ to 125°C | ; | 0 to 5.5 V | | | ±5 | μA |
| I _{off} | X1, Y | $V_1 \text{ or } V_0 = 5.5 \text{ V}$ | $T_{A} = -40^{\circ}C$ to 125°C | ; | 0 | | | ±10 | μA |
| I _{CC} | | $V_{I} = 5.5 \text{ V or GND}, I_{O} = 0$ | $T_{A} = -40^{\circ}C$ to 125°C | : | 1.65 V to 5.5 V | | | 10 | μA |
| Ci | | $V_{I} = V_{CC}$ or GND | | | 3.3 V | | 7 | | pF |

(1) All typical values are at $V_{CC} = 3.3$ V, $T_A = 25^{\circ}C$.

SN74LVC1GX04

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TRUMENTS

XAS

6.6 Switching Characteristics, SN74LVC1GX04

over recommended operating free-air temperature range, $C_L = 15 \text{ pF}$ (unless otherwise noted) (see Figure 2)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | TEMPERATURE | V _{cc} | MIN | MAX | UNIT |
|-----------------|-----------------|------------------|---------------|---|-----|-----|------|
| | | | | $V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$ | 1 | 4 | |
| | | X2 | –40°C to 85°C | $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$ | 0.8 | 2.6 | |
| | X1 | Y ⁽¹⁾ | -40 C 10 85 C | $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | 0.6 | 2.4 | |
| | | | | $V_{CC} = 5 V \pm 0.5 V$ | 0.5 | 2 | |
| t _{pd} | | | | $V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$ | 3.5 | 10 | ns |
| | | | | $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$ | 2.2 | 6 | |
| | | | –40°C to 85°C | $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | 2 | 5 | |
| | | | | $V_{CC} = 5 V \pm 0.5 V$ | 1.5 | 3.5 | |

(1) X2 – no external load

6.7 Switching Characteristics, SN74LVC1GX04

over recommended operating free-air temperature range, $C_L = 30 \text{ pF}$ or 50 pF (unless otherwise noted) (see Figure 3)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | TEMPERATURE | V _{cc} | MIN | МАХ | UNIT |
|-----------------|-----------------|------------------|---------------|---|-----|-----|------|
| | | | | $V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$ | 1.1 | 7 | |
| | | ×2 | 10°C to 95°C | $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$ | 0.8 | 4 | |
| | X1 – | Y ⁽¹⁾ | –40°C to 85°C | $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | 0.8 | 3.7 | |
| | | | | $V_{CC} = 5 V \pm 0.5 V$ | 0.8 | 3 | |
| t _{pd} | | | –40°C to 85°C | $V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$ | 3.8 | 18 | ns |
| | | | | $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$ | 2 | 7.4 | |
| | | | | $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | 2 | 7.8 | |
| | | | | $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$ | 2 | 5 | |

(1) X2 - no external load

6.8 Switching Characteristics, SN74LVC1GX04

over recommended operating free-air temperature range, C_L = 30 pF or 50 pF (unless otherwise noted) (see Figure 3)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | TEMPERATURE | V _{cc} | MIN | МАХ | UNIT |
|--------------------|------------------|----------------|---|---|-----|-----|------|
| | | | | $V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$ | 1.1 | 8 | |
| | | X2 | 1000 - 10700 | $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$ | 0.8 | 5 | |
| t _{pd} X1 | Y ⁽¹⁾ | –40°C to 125°C | $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | 0.8 | 4.3 | | |
| | | | $V_{CC} = 5 V \pm 0.5 V$ | 0.8 | 3.5 | | |
| | | 40%0 to 405%0 | $V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$ | 3.8 | 20 | ns | |
| | | | $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$ | 2 | 8.4 | | |
| | | Ĭ, | -40°C to 125°C | $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | 2 | 8.8 | |
| | | | | $V_{CC} = 5 V \pm 0.5 V$ | 2 | 5.5 | |

(1) X2 - no external load

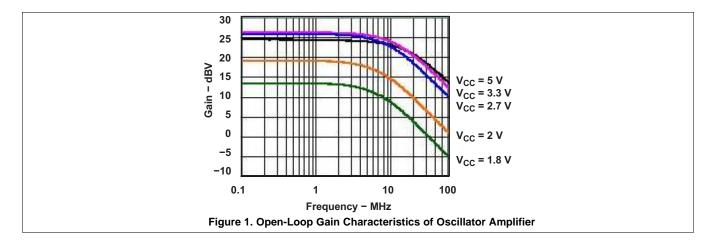
6.9 **Operating Characteristics**

 $T_A = 25^{\circ}C$

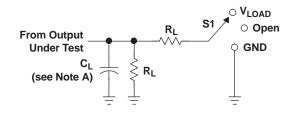
| | PARAMETER | TEST CONDITIONS | V _{cc} | TYP | UNIT |
|-----------------|---|--------------------|-------------------------|-----|------|
| | | | V _{CC} = 1.8 V | 22 | |
| | C _{pd} Power dissipation capacitance | | $V_{CC} = 2.5 V$ | 22 | |
| C _{pd} | | f = 10 MHz | V _{CC} = 3.3 V | 24 | pF |
| | | | $V_{CC} = 5 V$ | 35 | |



6.10 Typical Characteristics



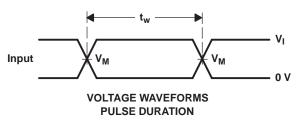
7 Parameter Measurement Information

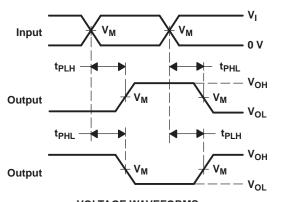


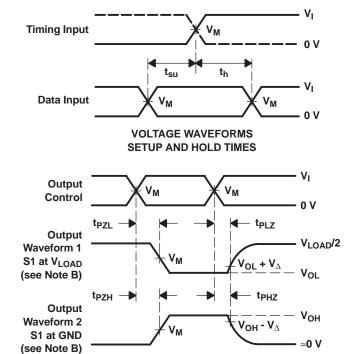
LOAD CIRCUIT

| TEST | S1 |
|------------------------------------|-------------------|
| t _{PLH} /t _{PHL} | Open |
| t _{PLZ} /t _{PZL} | V _{LOAD} |
| t _{PHZ} /t _{PZH} | GND |

| N N | INI | INPUTS | | | | - | |
|-------------------------------------|-----------------|--------------------------------|--------------------|-------------------|-------|--------------|--------------|
| V _{CC} | VI | t _r /t _f | V _M | V _{LOAD} | CL | RL | V_{Δ} |
| $1.8~V\pm0.15~V$ | V _{CC} | ≤2 ns | V _{CC} /2 | $2 \times V_{CC}$ | 15 pF | 1 Μ Ω | 0.15 V |
| $\textbf{2.5 V} \pm \textbf{0.2 V}$ | V _{CC} | ≤2 ns | V _{CC} /2 | $2 \times V_{CC}$ | 15 pF | 1 Μ Ω | 0.15 V |
| 3.3 V \pm 0.3 V | 3 V | ≤2.5 ns | 1.5 V | 6 V | 15 pF | 1 Μ Ω | 0.3 V |
| 5 V \pm 0.5 V | V _{CC} | ≤2.5 ns | V _{CC} /2 | $2 \times V_{CC}$ | 15 pF | 1 Μ Ω | 0.3 V |







VOLTAGE WAVEFORMS

ENABLE AND DISABLE TIMES

LOW- AND HIGH-LEVEL ENABLING

VOLTAGE WAVEFORMS PROPAGATION DELAY TIMES INVERTING AND NONINVERTING OUTPUTS

NOTES: A. C_L includes probe and jig capacitance.

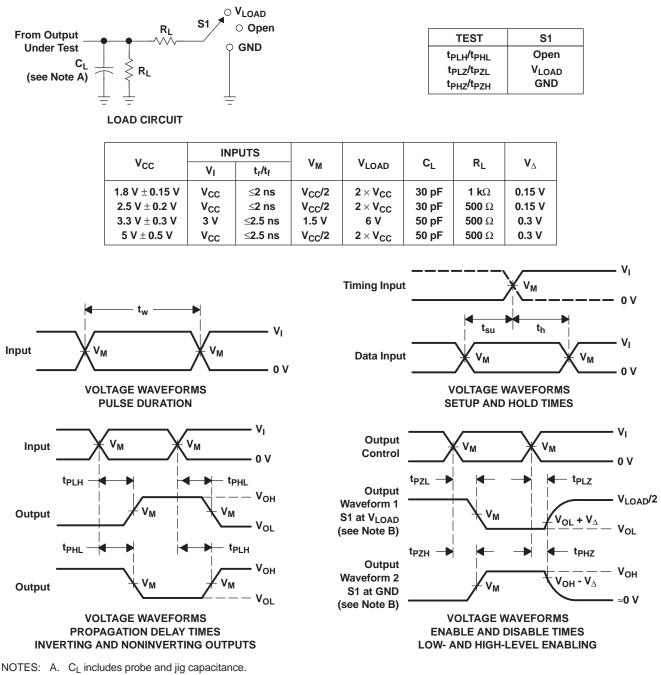
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_Q = 50 Ω.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms

8







- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z₀ = 50 Ω .
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms



8 Detailed Description

8.1 Overview

The SN74LVC1GX04 is optimized for creating a crystal oscillator circuit with a buffered square-wave output. This device is fully specified for partial-power-down applications using I_{off} (Y output only). The I_{off} circuitry disables the outputs, preventing damaging current back-flow through the device when it is powered down.

8.2 Functional Block Diagram

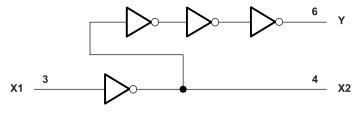


Figure 4. Logic Diagram (Positive Logic)

8.3 Feature Description

The first inverter is used as a linear amplifier for crystal oscillator.

The last three inverters ensure a fast edge square-wave at the Y output.

8.4 Device Functional Modes

The only intended device use is to generate a square-wave output using a crystal to set the operating frequency.

| INPUT X1 | OUTPUTS | | | | | |
|----------|---------|---|--|--|--|--|
| | X2 | Y | | | | |
| Н | L | Н | | | | |
| L | Н | L | | | | |

Table 1. Function Table



9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The SN74LVC1GX04 contains a buffered and unbuffered inverter for the specific purpose of creating a crystal oscillator and driver with limited external components.

9.2 Typical Application

Figure 5 shows a typical application of the SN74LVC1GX04 in a Pierce oscillator circuit. The buffered inverter (SN74LVC1G04 portion) produces a rail-to-rail voltage waveform. The recommended load for the crystal shown in this example is 16 pF. The value of the recommended load (C_L) can be found in the crystal manufacturer's data sheet.

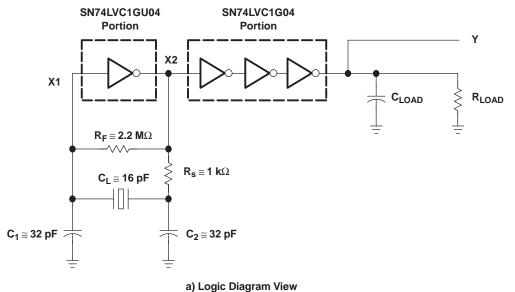
Values of C_1 and C_2 are chosen to calculate C_L in Equation 1 where $C_1 \equiv C_2$.

$$C_{L} = \frac{C_{1}C_{2}}{C_{1} + C_{2}}$$
(1)

 R_s is the current-limiting resistor, and the value depends on the maximum power dissipation of the crystal. Generally, the recommended value of R_s is specified in the crystal manufacturer's data sheet and, usually, this value is approximately equal to the reactance of C_2 at resonance frequency, that is seen in Equation 2.

$$R_s = X_{C_a}$$

 R_F is the feedback resistor that is used to bias the inverter in the linear region of operation. Usually, the value is chosen to be within 1 M Ω to 10 M Ω .



. _ _

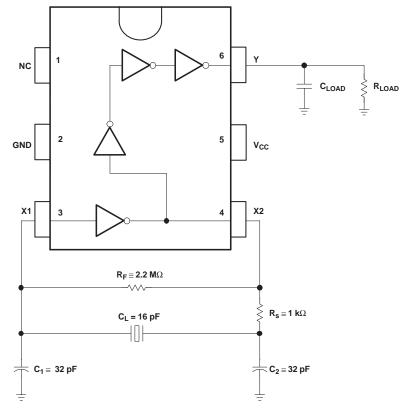
Figure 5. Oscillator Circuit

(2)

TEXAS INSTRUMENTS

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Typical Application (continued)



b) Oscillator Circuit in DBV or DCK Pinout

Figure 6. Oscillator Circuit (Continued)

9.2.1 Design Requirements

The open-loop gain of the unbuffered inverter decreases as power-supply voltage decreases. This decreases the closed-loop gain of the oscillator circuit. The value of R_s can be decreased to increase the closed-loop gain, while maintaining the power dissipation of the crystal within the maximum limit.

 R_s and C_2 form a low-pass filter and reduce spurious oscillations. Component values can be adjusted, based on the desired cutoff frequency.

 C_2 can be increased over C_1 to increase the phase shift and help in start-up of the oscillator. Increasing C_2 may affect the duty cycle of the output voltage.

At high frequency, phase shift due to R_s becomes significant. In this case, R_s can be replaced by a capacitor to reduce the phase shift.

9.2.2 Detailed Design Procedure

After the selection of proper component values, the oscillator circuit should be tested using these components. To ensure that the oscillator circuit performs within the *Recommended Operating Conditions*⁽¹⁾, follow these steps:

- 1. Without a crystal, the oscillator circuit should not oscillate. To check this, the crystal can be replaced by its equivalent parallel-resonant resistance.
- 2. When the power-supply voltage drops, the closed-loop gain of the oscillator circuit reduces. Ensure that the circuit oscillates at the appropriate frequency at the lowest V_{CC} and highest V_{CC} .
- 3. Ensure that the duty cycle, start-up time, and frequency drift over time is within the system requirements.
- All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, SCBA004.



Typical Application (continued)

9.2.3 Application Curve

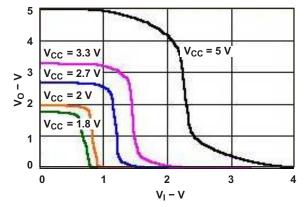


Figure 7. V_0 vs V_1 Characteristics of Oscillator Amplifier

10 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in *Recommended Operating Conditions*⁽¹⁾ table.

Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1- μ F capacitor is recommended. If there are multiple V_{CC} terminals then 0.01- μ F or 0.022- μ F capacitors are recommended for each power terminal. It is ok to parallel multiple bypass capacitors to reject different frequencies of noise. Multiple bypass capacitors may be paralleled to reject different frequencies of noise. The bypass capacitor should be installed as close to the power terminal as possible for the best results.



11 Layout

11.1 Layout Guidelines

When using multiple bit logic devices, inputs should not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states.

Specified in Figure 8 are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} , whichever makes more sense or is more convenient.

11.2 Layout Example



Figure 8. Layout Diagram

TEXAS INSTRUMENTS

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12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation, see the following: Implications of Slow or Floating CMOS Inputs, SCBA004

12.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E[™] Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.3 Trademarks

NanoStar, NanoFree, E2E are trademarks of Texas Instruments. All other trademarks are the property of their respective owners.

12.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material | MSL Peak Temp | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|--------------------|------|----------------|-----------------|-------------------------------|--------------------|--------------|--------------------------|---------|
| | | | | | | | (6) | | | | |
| 74LVC1GX04DCKRE4 | ACTIVE | SC70 | DCK | 6 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | (D25, D2J, D2K, D2 R) | Samples |
| 74LVC1GX04DCKTG4 | ACTIVE | SC70 | DCK | 6 | 250 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | (D25, D2R) | Samples |
| SN74LVC1GX04DBVR | ACTIVE | SOT-23 | DBV | 6 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | (CX45, CX4R) | Samples |
| SN74LVC1GX04DBVT | ACTIVE | SOT-23 | DBV | 6 | 250 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | (CX45, CX4R) | Samples |
| SN74LVC1GX04DCKR | ACTIVE | SC70 | DCK | 6 | 3000 | RoHS & Green | NIPDAU SN | Level-1-260C-UNLIM | -40 to 125 | (D25, D2J, D2K, D2 R) | Samples |
| SN74LVC1GX04DCKT | ACTIVE | SC70 | DCK | 6 | 250 | RoHS & Green | NIPDAU SN | Level-1-260C-UNLIM | -40 to 125 | (D25, D2J, D2R) | Samples |
| SN74LVC1GX04DRLR | ACTIVE | SOT-5X3 | DRL | 6 | 4000 | RoHS & Green | NIPDAU NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | (D27, D2R) | Samples |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



PACKAGE OPTION ADDENDUM

10-Dec-2020

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN74LVC1GX04 :

Enhanced Product: SN74LVC1GX04-EP

NOTE: Qualified Version Definitions:

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

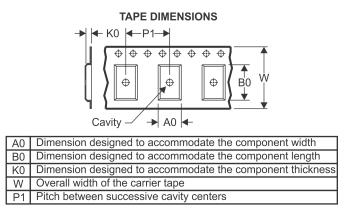
PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter | | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|------------------|-----------------|--------------------|------|------|------------------|---------|------------|------------|------------|------------|-----------|------------------|
| | | | | | (mm) | W1 (mm) | | | | | | |
| 74LVC1GX04DCKTG4 | SC70 | DCK | 6 | 250 | 180.0 | 8.4 | 2.47 | 2.3 | 1.25 | 4.0 | 8.0 | Q3 |
| SN74LVC1GX04DBVR | SOT-23 | DBV | 6 | 3000 | 180.0 | 8.4 | 3.23 | 3.17 | 1.37 | 4.0 | 8.0 | Q3 |
| SN74LVC1GX04DBVR | SOT-23 | DBV | 6 | 3000 | 178.0 | 9.2 | 3.3 | 3.23 | 1.55 | 4.0 | 8.0 | Q3 |
| SN74LVC1GX04DBVT | SOT-23 | DBV | 6 | 250 | 178.0 | 9.2 | 3.3 | 3.23 | 1.55 | 4.0 | 8.0 | Q3 |
| SN74LVC1GX04DBVT | SOT-23 | DBV | 6 | 250 | 180.0 | 8.4 | 3.23 | 3.17 | 1.37 | 4.0 | 8.0 | Q3 |
| SN74LVC1GX04DCKR | SC70 | DCK | 6 | 3000 | 178.0 | 9.2 | 2.4 | 2.4 | 1.22 | 4.0 | 8.0 | Q3 |
| SN74LVC1GX04DCKR | SC70 | DCK | 6 | 3000 | 178.0 | 9.0 | 2.4 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |
| SN74LVC1GX04DCKR | SC70 | DCK | 6 | 3000 | 180.0 | 8.4 | 2.41 | 2.41 | 1.2 | 4.0 | 8.0 | Q3 |
| SN74LVC1GX04DCKT | SC70 | DCK | 6 | 250 | 178.0 | 9.2 | 2.4 | 2.4 | 1.22 | 4.0 | 8.0 | Q3 |
| SN74LVC1GX04DCKT | SC70 | DCK | 6 | 250 | 180.0 | 8.4 | 2.41 | 2.41 | 1.2 | 4.0 | 8.0 | Q3 |
| SN74LVC1GX04DCKT | SC70 | DCK | 6 | 250 | 178.0 | 9.0 | 2.4 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |
| SN74LVC1GX04DRLR | SOT-5X3 | DRL | 6 | 4000 | 180.0 | 8.4 | 1.98 | 1.78 | 0.69 | 4.0 | 8.0 | Q3 |
| SN74LVC1GX04DRLR | SOT-5X3 | DRL | 6 | 4000 | 180.0 | 9.5 | 1.78 | 1.78 | 0.69 | 4.0 | 8.0 | Q3 |

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PACKAGE MATERIALS INFORMATION

24-Jul-2020



| *All dimensions are nominal | | | | | | | |
|-----------------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
| 74LVC1GX04DCKTG4 | SC70 | DCK | 6 | 250 | 183.0 | 183.0 | 20.0 |
| SN74LVC1GX04DBVR | SOT-23 | DBV | 6 | 3000 | 202.0 | 201.0 | 28.0 |
| SN74LVC1GX04DBVR | SOT-23 | DBV | 6 | 3000 | 180.0 | 180.0 | 18.0 |
| SN74LVC1GX04DBVT | SOT-23 | DBV | 6 | 250 | 180.0 | 180.0 | 18.0 |
| SN74LVC1GX04DBVT | SOT-23 | DBV | 6 | 250 | 202.0 | 201.0 | 28.0 |
| SN74LVC1GX04DCKR | SC70 | DCK | 6 | 3000 | 180.0 | 180.0 | 18.0 |
| SN74LVC1GX04DCKR | SC70 | DCK | 6 | 3000 | 180.0 | 180.0 | 18.0 |
| SN74LVC1GX04DCKR | SC70 | DCK | 6 | 3000 | 202.0 | 201.0 | 28.0 |
| SN74LVC1GX04DCKT | SC70 | DCK | 6 | 250 | 180.0 | 180.0 | 18.0 |
| SN74LVC1GX04DCKT | SC70 | DCK | 6 | 250 | 202.0 | 201.0 | 28.0 |
| SN74LVC1GX04DCKT | SC70 | DCK | 6 | 250 | 180.0 | 180.0 | 18.0 |
| SN74LVC1GX04DRLR | SOT-5X3 | DRL | 6 | 4000 | 202.0 | 201.0 | 28.0 |
| SN74LVC1GX04DRLR | SOT-5X3 | DRL | 6 | 4000 | 184.0 | 184.0 | 19.0 |

DCK (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-203 variation AB.



LAND PATTERN DATA



NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



DBV0006A



PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.2. This drawing is subject to change without notice.3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

- 4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation. 5. Refernce JEDEC MO-178.



DBV0006A

EXAMPLE BOARD LAYOUT

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

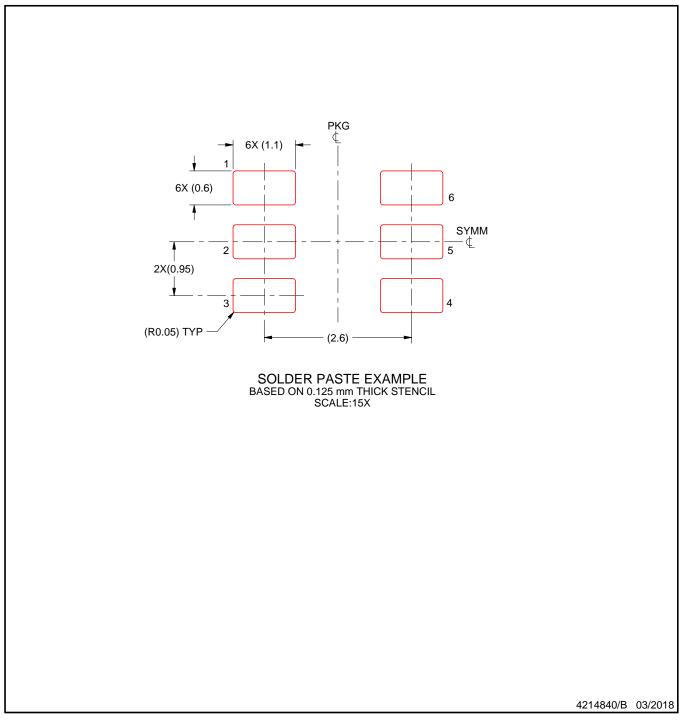


DBV0006A

EXAMPLE STENCIL DESIGN

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



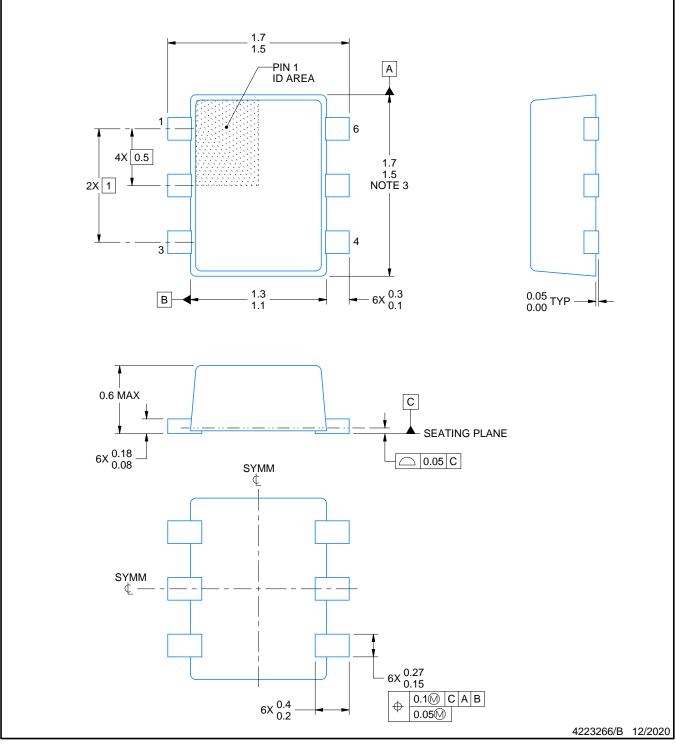
DRL0006A



PACKAGE OUTLINE

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side. 4. Reference JEDEC registration MO-293 Variation UAAD

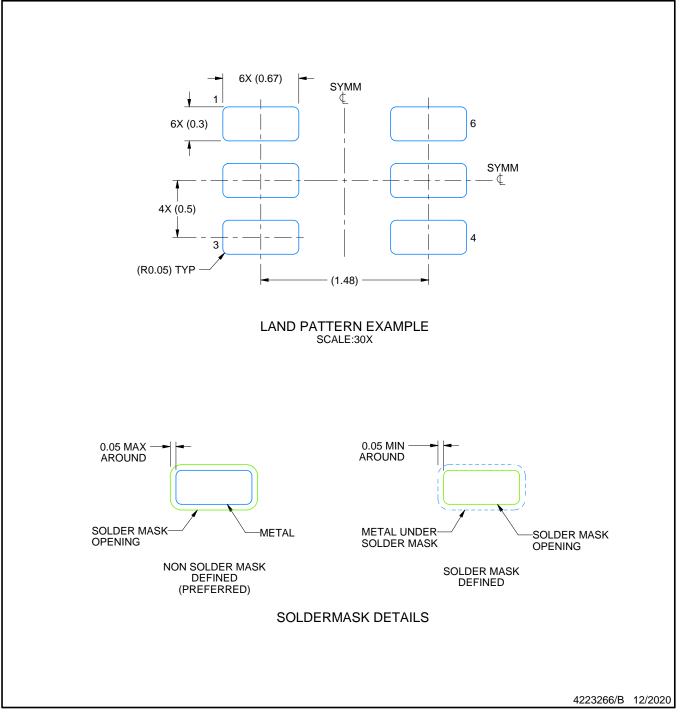


DRL0006A

EXAMPLE BOARD LAYOUT

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

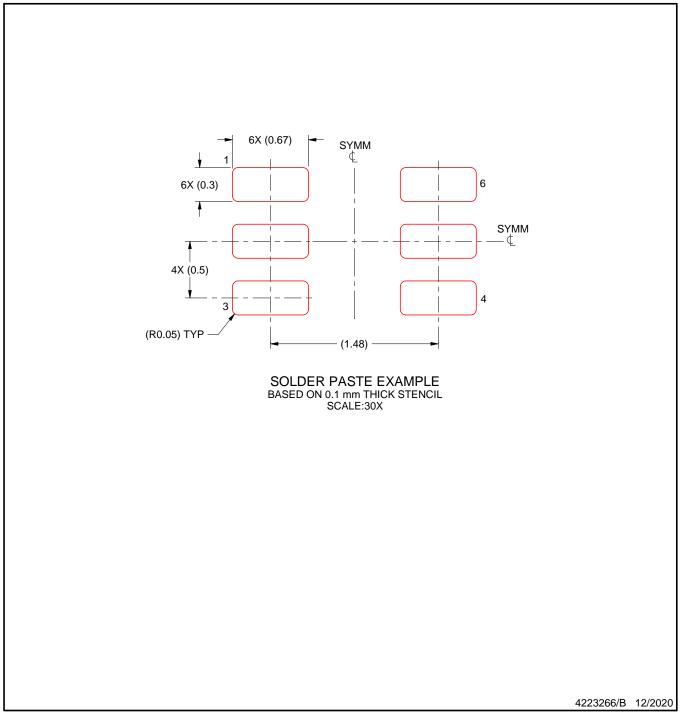


DRL0006A

EXAMPLE STENCIL DESIGN

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

8. Board assembly site may have different recommendations for stencil design.



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